1. Product profile

1.1 General description
Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features
- Average forward current: $I_{F(AV)} \leq 2$ A
- Reverse voltage: $V_R \leq 30$ V
- Low forward voltage
- High power capability due to clip-bond technology
- AEC-Q101 qualified
- Small and flat lead SMD plastic package

1.3 Applications
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$I_{F(AV)}$</td>
<td>average forward current</td>
<td>square wave; $\delta = 0.5$; $f = 20$ kHz $T_{amb} \leq 90$ °C</td>
<td>-</td>
<td>-</td>
<td>2</td>
<td>A</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$T_{sp} \leq 140$ °C</td>
<td>-</td>
<td>-</td>
<td>2</td>
<td>A</td>
</tr>
<tr>
<td>$V_R$</td>
<td>reverse voltage</td>
<td>-</td>
<td>-</td>
<td>-</td>
<td>30</td>
<td>V</td>
</tr>
<tr>
<td>$V_F$</td>
<td>forward voltage</td>
<td>$I_F = 2$ A</td>
<td>-</td>
<td>365</td>
<td>420</td>
<td>mV</td>
</tr>
<tr>
<td>$I_R$</td>
<td>reverse current</td>
<td>$V_R = 30$ V</td>
<td>-</td>
<td>0.6</td>
<td>1.5</td>
<td>mA</td>
</tr>
</tbody>
</table>

2. Pinning information

Table 2. Pinning

<table>
<thead>
<tr>
<th>Pin</th>
<th>Description</th>
<th>Simplified outline</th>
<th>Graphic symbol</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>cathode</td>
<td><img src="symbol001" alt="Pinning Diagram" /></td>
<td>1 2</td>
</tr>
<tr>
<td>2</td>
<td>anode</td>
<td>sym001</td>
<td></td>
</tr>
</tbody>
</table>

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package Name</th>
<th>Description</th>
<th>Version</th>
</tr>
</thead>
<tbody>
<tr>
<td>PMEG3020ER</td>
<td>-</td>
<td>plastic surface-mounted package; 2 leads</td>
<td>SOD123W</td>
</tr>
</tbody>
</table>

4. Marking

Table 4. Marking codes

<table>
<thead>
<tr>
<th>Type number</th>
<th>Marking code</th>
</tr>
</thead>
<tbody>
<tr>
<td>PMEG3020ER</td>
<td>B9</td>
</tr>
</tbody>
</table>

5. Limiting values

Table 5. Limiting values

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_R$</td>
<td>reverse voltage</td>
<td>$T_J = 25 , ^\circ C$</td>
<td>-</td>
<td>30</td>
<td>V</td>
</tr>
<tr>
<td>$I_{F(AV)}$</td>
<td>average forward current</td>
<td>square wave; $\delta = 0.5$; $f = 20 , \text{kHz}$</td>
<td>$T_{amb} \leq 90 , ^\circ C$</td>
<td>1</td>
<td>2</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$T_{amb} \leq 140 , ^\circ C$</td>
<td>-</td>
<td>2</td>
<td>A</td>
</tr>
<tr>
<td>$I_{FSM}$</td>
<td>non-repetitive peak forward current</td>
<td>square wave; $t_p = 8 , \text{ms}$</td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>[3][4]</td>
<td>0.57</td>
</tr>
<tr>
<td>$P_{tot}$</td>
<td>total power dissipation</td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>[3][5]</td>
<td>0.95</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>-</td>
<td>1.8</td>
<td>W</td>
</tr>
</tbody>
</table>
2 A low V\(_F\) MEGA Schottky barrier rectifier

### Table 5. Limiting values ...continued
*In accordance with the Absolute Maximum Rating System (IEC 60134).*

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>(T_J)</td>
<td>junction temperature</td>
<td>-</td>
<td>150</td>
<td>°C</td>
<td></td>
</tr>
<tr>
<td>(T_{amb})</td>
<td>ambient temperature</td>
<td>-55</td>
<td>150</td>
<td>°C</td>
<td></td>
</tr>
<tr>
<td>(T_{stg})</td>
<td>storage temperature</td>
<td>-65</td>
<td>150</td>
<td>°C</td>
<td></td>
</tr>
</tbody>
</table>

[2] \(T_J = 25\) °C prior to surge.
[3] Reflow soldering is the only recommended soldering method.
[5] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm\(^2\).

### Table 6. Thermal characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>(R_{th(j-a)})</td>
<td>thermal resistance from junction to ambient</td>
<td>in free air</td>
<td>-(^{[1][2]})</td>
<td>-</td>
<td>-</td>
<td>220 K/W</td>
</tr>
<tr>
<td>(R_{th(j-sp)})</td>
<td>thermal resistance from junction to solder point</td>
<td>-(^{[6]})</td>
<td>-</td>
<td>-</td>
<td>18</td>
<td>K/W</td>
</tr>
</tbody>
</table>

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses \(P_R\) are a significant part of the total power losses.
[2] Reflow soldering is the only recommended soldering method.
[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm\(^2\).
2 A low \( V_F \) MEGA Schottky barrier rectifier

**Fig 1.** Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

**Fig 2.** Transient thermal impedance from junction to ambient as a function of pulse duration; typical values
7. Characteristics

Table 7. Characteristics
\( T_j = 25 \, ^\circ\text{C} \) unless otherwise specified.

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_F )</td>
<td>forward voltage</td>
<td>( I_F = 0.1 , \text{A} )</td>
<td>-</td>
<td>230</td>
<td>260</td>
<td>mV</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( I_F = 1 , \text{A} )</td>
<td>-</td>
<td>320</td>
<td>360</td>
<td>mV</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( I_F = 1.5 , \text{A} )</td>
<td>-</td>
<td>340</td>
<td>380</td>
<td>mV</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( I_F = 2 , \text{A} )</td>
<td>-</td>
<td>365</td>
<td>420</td>
<td>mV</td>
</tr>
<tr>
<td>( I_R )</td>
<td>reverse current</td>
<td>( V_R = 5 , \text{V} )</td>
<td>-</td>
<td>55</td>
<td>-</td>
<td>( \mu \text{A} )</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_R = 30 , \text{V} )</td>
<td>-</td>
<td>0.6</td>
<td>1.5</td>
<td>mA</td>
</tr>
<tr>
<td>( C_d )</td>
<td>diode capacitance</td>
<td>( f = 1 , \text{MHz} )</td>
<td>( V_R = 1 , \text{V} )</td>
<td>-</td>
<td>170</td>
<td>pF</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_R = 10 , \text{V} )</td>
<td>-</td>
<td>60</td>
<td>-</td>
<td>pF</td>
</tr>
</tbody>
</table>
2 A low V_F MEGA Schottky barrier rectifier

Fig 4. Forward current as a function of forward voltage; typical values

1. $T_J = 150 \, ^\circ C$
2. $T_J = 125 \, ^\circ C$
3. $T_J = 85 \, ^\circ C$
4. $T_J = 25 \, ^\circ C$
5. $T_J = -40 \, ^\circ C$

Fig 5. Reverse current as a function of reverse voltage; typical values

1. $T_J = 125 \, ^\circ C$
2. $T_J = 85 \, ^\circ C$
3. $T_J = 25 \, ^\circ C$
4. $T_J = -40 \, ^\circ C$

Fig 6. Diode capacitance as a function of reverse voltage; typical values

- $f = 1 \, MHz$
- $T_{amb} = 25 \, ^\circ C$
2 A low $V_F$ MEGA Schottky barrier rectifier

$T_j = 150 \, ^\circ C$

1. $\delta = 0.1$
2. $\delta = 0.2$
3. $\delta = 0.5$
4. $\delta = 1$

**Fig 7.** Average forward power dissipation as a function of average forward current; typical values

$T_j = 125 \, ^\circ C$

1. $\delta = 1$
2. $\delta = 0.9$
3. $\delta = 0.8$
4. $\delta = 0.5$

**Fig 8.** Average reverse power dissipation as a function of reverse voltage; typical values

FR4 PCB, standard footprint

$T_j = 150 \, ^\circ C$

1. $\delta = 1; \text{ DC}$
2. $\delta = 0.5; f = 20 \, kHz$
3. $\delta = 0.2; f = 20 \, kHz$
4. $\delta = 0.1; f = 20 \, kHz$

**Fig 9.** Average forward current as a function of ambient temperature; typical values

FR4 PCB, mounting pad for cathode $1 \, cm^2$

$T_j = 150 \, ^\circ C$

1. $\delta = 1; \text{ DC}$
2. $\delta = 0.5; f = 20 \, kHz$
3. $\delta = 0.2; f = 20 \, kHz$
4. $\delta = 0.1; f = 20 \, kHz$

**Fig 10.** Average forward current as a function of ambient temperature; typical values
2 A low V_f MEGA Schottky barrier rectifier

Fig 11. Average forward current as a function of ambient temperature; typical values

Ceramic PCB, Al_2O_3, standard footprint

\( T_j = 150 \, ^\circ C \)

(1) \( \delta = 1; \) DC
(2) \( \delta = 0.5; f = 20 \, kHz \)
(3) \( \delta = 0.2; f = 20 \, kHz \)
(4) \( \delta = 0.1; f = 20 \, kHz \)

Fig 12. Average forward current as a function of solder point temperature; typical values

\( T_j = 150 \, ^\circ C \)

(1) \( \delta = 1; \) DC
(2) \( \delta = 0.5; f = 20 \, kHz \)
(3) \( \delta = 0.2; f = 20 \, kHz \)
(4) \( \delta = 0.1; f = 20 \, kHz \)
8. Test information

The current ratings for the typical waveforms as shown in Figure 9, 10, 11 and 12 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with $I_M$ defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with $I_{RMS}$ defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline

![Package outline SOD123W](image)
10. Packing information

Table 8. Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>Description</th>
<th>Packing quantity</th>
</tr>
</thead>
<tbody>
<tr>
<td>PMEG3020ER</td>
<td>SOD123W</td>
<td>4 mm pitch, 8 mm tape and reel</td>
<td>3000 -115</td>
</tr>
</tbody>
</table>

[1] For further information and the availability of packing methods, see Section 14.

11. Soldering

Reflow soldering is the only recommended soldering method.

Fig 15. Reflow soldering footprint SOD123W
## 12. Revision history

<table>
<thead>
<tr>
<th>Document ID</th>
<th>Release date</th>
<th>Data sheet status</th>
<th>Change notice</th>
<th>Supersedes</th>
</tr>
</thead>
<tbody>
<tr>
<td>PMEG3020ER_1</td>
<td>20081229</td>
<td>Product data sheet</td>
<td>-</td>
<td>-</td>
</tr>
</tbody>
</table>

2 A low $V_F$ MEGA Schottky barrier rectifier

NXP Semiconductors
13. Legal information

13.1 Data sheet status

<table>
<thead>
<tr>
<th>Document status</th>
<th>Product status</th>
<th>Definition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Objective [short] data sheet</td>
<td>Development</td>
<td>This document contains data from the objective specification for product development.</td>
</tr>
<tr>
<td>Preliminary [short] data sheet</td>
<td>Qualification</td>
<td>This document contains data from the preliminary specification.</td>
</tr>
<tr>
<td>Product [short] data sheet</td>
<td>Production</td>
<td>This document contains the product specification.</td>
</tr>
</tbody>
</table>

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section “Definitions”.
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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